

Features

- Lead free product is acquired
- Surface mount package
- P-Channel switch with low $R_{DS(on)}$
- Operated at low logic level gate drive
- ESD protected gate
- Complementary to TPM2008EP3

Package and Pin Configuration

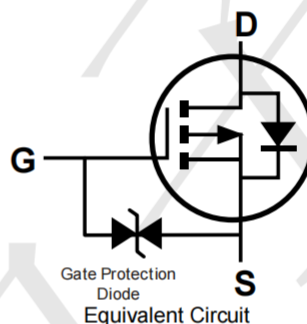


DFN1006-3L

Application

- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

Circuit diagram



Marking: U4

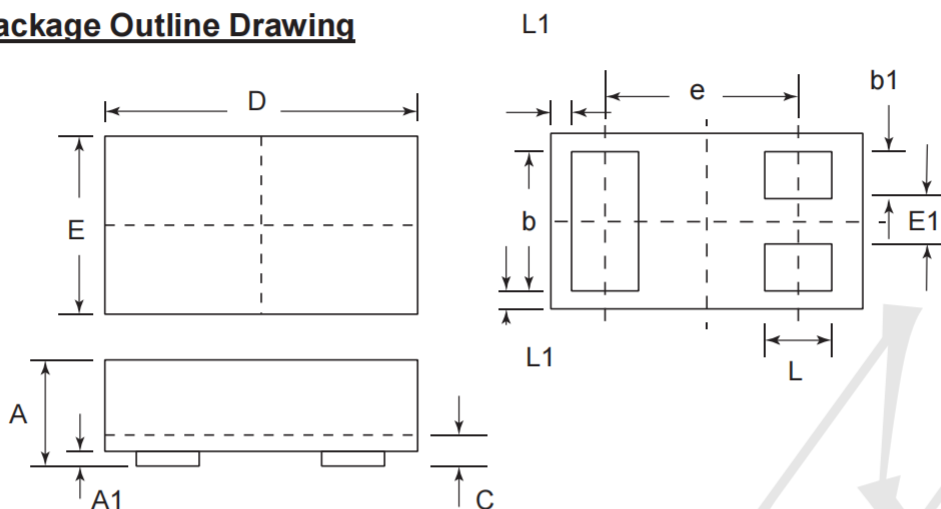
Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	-20	V
Typical gate-source voltage	V_{GS}	± 12	V
Continuous drain current (note 1)	I_D	-0.66	A
Pulsed drain current ($t_p=10\mu\text{s}$)	I_{DM}	-1.2	A
Power dissipation (note 2)	P_D	100	mW
Thermal resistance from junction to ambient (note 1)	$R_{\theta JA}$	1250	$^{\circ}\text{C/W}$
Junction temperature range	T_J	150	$^{\circ}\text{C}$
Storage temperature range	T_{STG}	-55 ~ +150	$^{\circ}\text{C}$
Lead temperature for soldering purposes (1/8" from case for 10s)	T_L	260	$^{\circ}\text{C}$

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

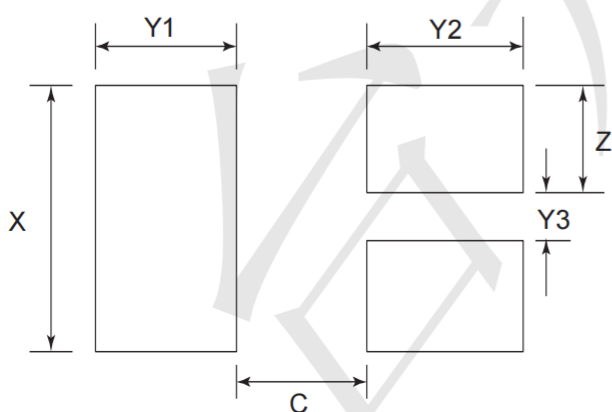
A						
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
STATIC PARAMETERS						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-20			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -20V, V_{GS} = 0V$			-1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 10V, V_{DS} = 0V$			± 20	μA
Gate threshold voltage (note 2)	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-0.35		-1.1	V
Drain-source on-resistance (note 2)	$R_{DS(on)}$	$V_{GS} = -4.5V, I_D = -1A$			520	m Ω
		$V_{GS} = -2.5V, I_D = -0.8A$			700	
		$V_{GS} = -1.8V, I_D = -0.5A$		950		
Forward tranconductance (note 2)	g_{FS}	$V_{DS} = -10V, I_D = -0.54A$		1.2		S
Diode forward voltage	V_{SD}	$I_S = -0.5A, V_{GS} = 0V$			-1.2	V
DYNAMIC PARAMETERS (note 4)						
Input capacitance	C_{iss}	$V_{DS} = -16V, V_{GS} = 0V, f = 1MHz$		113	170	pF
Output capacitance	C_{oss}			15	25	
Reverse transfer capacitance	C_{rss}			9	15	
SWITCHING PARAMETERS (note 4)						
Turn-on delay time (note 3)	$t_{d(on)}$	$V_{GS} = -4.5V, V_{DS} = -10V, I_D = -200mA, R_{GEN} = 10\Omega$		9		ns
Turn-on rise time (note 3)	t_r			5.8		
Turn-off delay time (note 3)	$t_{d(off)}$			32.7		
Turn-off fall time (note 3)	t_f			20.3		

DFN1006-3L Package Outline Drawing



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
b1	0.10	0.15	0.20	0.004	0.006	0.008
C	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
E1	0.15	0.20	0.25	0.006	0.008	0.010
L	0.20	0.25	0.30	0.008	0.010	0.012
L1	0.05 REF			0.0002 REF		

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
C	0.25	0.010
X	0.65	0.024
Y1	0.50	0.020
Y2	0.50	0.020
Y3	0.25	0.010
Z	0.20	0.008

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